The documentation and process conversion measures necessary to comply with this revision shall be completed by 10 January 1998.

INCH POUND

MIL-PRF-19500/115J 10 October 1997 SUPERSEDING MIL-S-19500/115H 20 December 1993

PERFORMANCE SPECIFICATION SHEET

SEMICONDUCTOR DEVICE, DIODE, SILICON, VOLTAGE REGULATOR TYPES
1N3821A THROUGH 1N3828A, 1N3016B THROUGH 1N3051B,
1N3821A-1 THROUGH 1N3828A-1, 1N3016B-1 THROUGH 1N3051B-1,
1N3821AUR-1 THROUGH 1N3828AUR-1, 1N3016BUR-1 THROUGH 1N3051BUR-1,
PLUS C- AND D- TOLERANCE SUFFIX,
JAN, JANTX, JANTXV, AND JANHC

This specification is approved for use by all Departments and Agencies of the Department of Defense.

- 1. SCOPE
- 1.1 <u>Scope</u>. This specification covers the performance requirements for 1 W, silicon, voltage regulator diodes with voltage tolerances of 5 percent, 2 percent, and 1 percent. Three levels of product assurance are provided for each device type as specified in MIL-PRF-19500. One level of product assurance is provided for die.
 - 1.2 Physical dimensions. See figures 1 (D0-13), 2 (D0-41), 3 (D0-213AB), 4, and 5 (JANHC).
 - 1.3 <u>Maximum ratings</u>. Maximum ratings are as shown in columns 8 and 10 of table IV herein and as follows: P_T = 1.0 W (D0-13 and D0-41) at T_L = +95°C, L = .375 (9.53 mm); both ends of case or diode body to heat sink at L = .375 (9.53 mm). (Derate I_Z to 0.0 mA dc at T_L = +175°C).

 $P_T = 1.W (D0-213AB)$ at $T_{EC} = +125^{\circ}C$. (Derate to 0 at $T_{EC} = +175^{\circ}C$).

 $-55^{\circ}C \leq T_{\mbox{\scriptsize OP}} \, \leq +175^{\circ}C; \, -55^{\circ}C \leq T_{\mbox{\scriptsize STG}} \leq +175^{\circ}C.$

1.4 Primary electrical characteristics. Primary electrical characteristic columns 2, 9, 12, and 15 of table IV herein and as follows:

 $3.3 \text{ V dc} \le V_Z \le 200 \text{ V dc}.$

A and B suffix devices are 5 percent voltage tolerance.

C suffix devices are 2 percent voltage tolerance.

D suffix devices are 1 percent voltage tolerance.

 $R_{\theta, JI} = 80^{\circ} \text{C/W} \text{ (maximum) at L} = .375 \text{ inch (9.53 mm) (D0-13)}.$

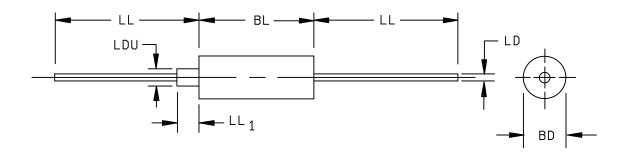
 $R_{\rm H,II} = 50^{\circ} \text{C/W}$ (maximum) at L = .375 inch (9.53 mm) (D0-41).

 $R_{\theta JEC} = 50^{\circ}C/W$ (maximum) junction to endcaps (D0-213AB).

Beneficial comments (recommendations, additions, deletions) and any pertinent data which may be of use in improving this document should be addressed to: Commander, Defense Supply Center Columbus, ATTN: DSCC-VAT, 3990 East Broad St., Columbus, OH 43216-5000, by using the addressed Standardization Document Improvement Proposal (DD Form 1426) appearing at the end of this document or by letter.

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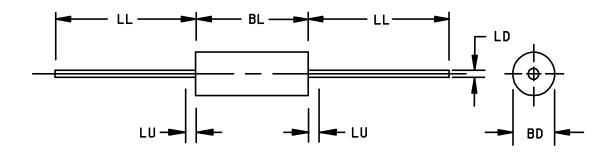
FSC 5961



	Incl	hes	Millim	neters	
Ltr	Min	Max	Min	Max	Notes
LD			0.66	0.89	
BD	.215 .265		5.46	6.73	4
LDU		.110		2.79	
BL	.195	.350	4.96	8.89	
LL ₁		.21		5.33	
LL	1.000		25.40		

- 1. Dimensions are in inches.
- Metric equivalents are given for general information only.
 Dimension BD shall be measured at the largest diameter.
- 4. Cathode lead shall be electrically connected to the case. If tubulation is used, it shall be on the anode end.

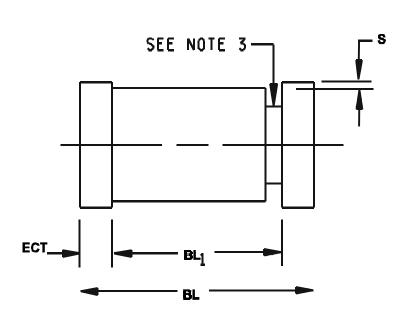
FIGURE 1. Semiconductor device, diode, types 1N3821A, C, D through 1N3828A, C, D and 1N3016B, C, D through 1N3051B, C,D.

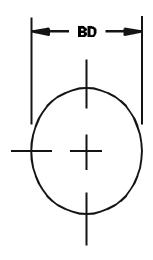


		Dime	nsions		
	Incl	hes	Millim	eters	
Ltr	Min	Max	Min	Max	Notes
LD	.028	.034	0.71	0.86	
BD	.080	.107	2.03	2.72	3
BL	.160	.205	4.06	5.21	3
LL	1.000		25.40		
LU		.050		1.27	4

- 1. Dimensions are in inches.
- 2. Metric equivalents are given for general information only.
- 3. Package contour optional within BD and length BL. Heat slugs, if any, shall be included within this cylinder but shall not be subject to minimum limit of BD.
- 4. Within this zone lead, diameter may vary to allow for lead finishes and irregularities other than heat slugs.

FIGURE 2. Physical dimensions, types 1N3821A-1, C-1, and D-1 through 1N3828A-1, C-1, and D-1; 1N3016B-1, C-1, and D-1 through 1N3051B-1, C-1, and D-1 (DO-41).

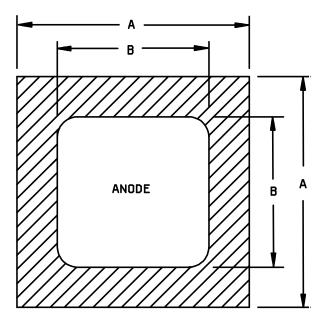




	Dimensions										
Ltr	Incl	hes	Millim	neters							
	Min	Max	Min	Max							
BL	.189	.205	4.80	5.21							
BD	.094	.105	2.39	2.67							
BL ₁	.159		4.04								
	(Ref.)		(Ref.)								
ECT	.014	.022	.360	.560							
S	.001		.030								

- 1. Dimensions are in inches.
- 2. Metric equivalents are given for general information only.
- 3. Gap not controlled, shape of body and gap not controlled.

FIGURE 3. Physical dimensions of surface mount family types 1N3821AUR-1, CUR-1, and DUR-1, through 1N3828AUR-1, CUR-1, and DUR-1 and 1N3016BUR-1, CUR-1, and DUR-1 through 1N3051BUR-1, CUR-1, and DUR-1 (DO-213AB).

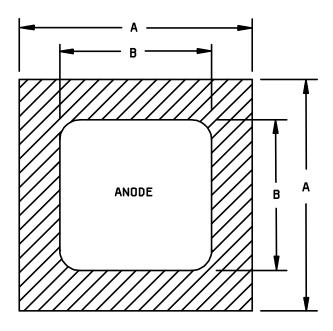


A Version

	Dimensions										
	Inc	hes	Millimeters								
Ltr	Min	Max	Min	Max							
Α	.035	.039	.89	.99							
В	.031	.033	.79	.84							

- 1. Dimensions are in inches.
- Difficulties
 Metric equivalents are given for general information only.
 The physical characteristics of the die thickness are .010 ± 002 (0.25 mm). Metallization is:
 Top (anode) Al, back (cathode) Au. Al thickness = 25,000Å minimum, Au thickness = 4000Å minimum.

FIGURE 4. Physical dimensions JANHCA die.



BACKSIDE IS CATHODE

B Version

	Dimensions										
	Inc	hes	Millimeters								
Ltr	Min	Max	Min	Max							
Α	.035	.039	.89	.99							
В	.027	.031	0.68	0.79							

- 1. Dimensions are in inches.
- 2. Metric equivalents are given for general information only.

 3. The physical characteristics of the die thickness are .012 \pm 002 (0.30 mm). Metallization is: Top (anode) - Al, back (cathode) - Au. Al thickness = 40,000Å minimum, Au thickness = 5000Å minimum.

FIGURE 5. Physical dimensions JANHCB die.

2. APPLICABLE DOCUMENTS

- 2.1 <u>General</u>. The documents listed in this section are specified in sections 3 and 4 of this specification. This section does not include documents cited in other sections of this specification or recommended for additional information or as examples. While every effort has been made to ensure the completeness of this list, document users are cautioned that they must meet all specified requirements documents cited in sections 3 and 4 of this specification, whether or not they are listed.
- 2.2 <u>Specifications, standards, and handbooks</u>. The following specifications, standards, and handbooks form a part of this document to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DODISS) and supplement thereto, cited in the solicitation (see 6.2).

SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-19500 - Semiconductor Devices, General Specification for.

STANDARD

MILITARY

MIL-STD-750 - Test Methods for Semiconductor Devices.

(Unless otherwise indicated, copies of the above specifications, standards, and handbooks are available from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

- 2.3 <u>Order of precedence</u>. In the event of a conflict between the text of this document and the references cited herein (except for related associated specifications or specification sheets), the text of this document takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.
 - 3. REQUIREMENTS
 - 3.1 Associated specification. The individual item requirements shall be in accordance with MIL-PRF-19500, and as specified herein.
- 3.2 <u>Interface requirements and physical dimensions</u>. The Interface requirements and physical dimensions shall be as specified in MIL-PRF-19500, and figures 1 (DO-13), 2 (DO-41), 3 (D0-213AB), and figures 4 and 5 for (JANHC).
- 3.2.1 <u>Lead finish</u>. Lead finish shall be solderable in accordance with MIL-STD-750 and MIL-PRF-19500 where a choice of lead finish is desired, it shall be specified in the acquisition document (see 6.2).
- 3.2.2 <u>Dash one construction</u>. Dash one (-1) diodes shall be of metallurgically bonded double plug construction in accordance with MIL-PRF-19500.
 - 3.3 Marking. Marking shall be in accordance with MIL-PRF-19500.
- 3.3.1 <u>Marking of UR version devices</u>. For UR version devices only, all marking (except polarity) may be omitted from the body, but shall be retained on the initial container.
- 3.3.2 <u>Polarity</u>. For dash one or UR dash one, the polarity shall be indicated with a contrasting color band to denote the cathode end or alternately with a minimum of three contrasting color dots spaced evenly around the periphery at the cathode end.
- 3.4 <u>Selection of tight tolerance devices</u>. The C and D suffix devices shall be selected from JAN, JANTX, or JANTXV devices, which have successfully completed all applicable screening, and groups A, B, and C testing as 5 percent tolerance devices. All sublots of C and D suffix devices shall pass group A, subgroup 2, at tighter tolerances. Tighter tolerances for mounting clip temperature shall be maintained for reference purpose to establish correlation. For C and D tolerance levels, $T_L = 30 \pm 2^{\circ}C$ at 0.375° from body or equivalent.
- 3.5 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in 1.3, 1.4, and table I.
 - 3.6 Electrical test requirements. The electrical test requirements shall be the subgroups specified in 4.4.2 and 4.4.3.

- 4. VERIFICATION
- 4.1 <u>Classification of Inspections</u>. The inspection requirements specified herein are classified as follows:
 - a. Qualification inspection (see 4.2).
 - b. Screening (see 4.3)
 - c. Conformance inspection (see 4.4).
- 4.2 Qualification inspection. Qualification inspection shall be in accordance with MIL-PRF-19500, and as specified herein.
- 4.2.1 JANHC devices. JANHC devices shall be qualified in accordance with MIL-PRF-19500.
- 4.2.2 Construction verification. Cross sectional photos from 3 devices shall be submitted in the qualification report.
- 4.3 <u>Screening (JAN, JANTXV and JANTX levels only)</u>. Screening shall be in accordance with MIL-PRF-19500 (table IV), and as specified herein. The following measurements shall be made in accordance with table I herein. Devices that exceed the limits of table I herein shall not be acceptable.

Screen	<u>Measurement</u>	
(see table IV of MIL-PRF-19500)	JANTX and JANTXV levels	JAN level
3a	Temperature cycling	Temperature cycling (in accordance with MIL-PRF- 19500 JANTX level)
3c <u>1/</u>	Thermal impedance (see 4.5.5)	Thermal impedance (see 4.5.5)
9	Not applicable	Not applicable
11	I_{R1} and V_Z	
12	See 4.3.2, t=48 hours	
13 <u>2/</u>	$\Delta I_{R1} \le 100$ percent of initial reading or 50nA dc, whichever is greater	
	$\Delta V_Z \le \pm 2$ percent of initial reading	
	Subgroup 2 of table I herein	

- 1/ Thermal impedance may be performed any time after sealing provided temperature cycling is performed in accordance with MIL-PRF-19500, screen 3 prior to this thermal test.
- $\underline{2}/$ PDA = 5 percent for screen 13, applies to ΔI_{R1} , ΔV_{Z} . Thermal impedance ($Z_{\theta JX}$) is not required in screen 13.
- 4.3.1 Screening (JANHC). Screening of JANHC die shall be in accordance with MIL-PRF-19500.
- 4.3.2 <u>Power burn-in conditions</u>. Power burn-in conditions are as follows: $I_Z = \text{column 8 of table IV minimum}$; mounting and test conditions in accordance with MIL-STD-750, method 1038, test condition B, TEC = +75°C to +100°C for surface mount devices. To better utilize burn-in equipment, higher values of I_Z shall be permitted provided:
 - a. The junction temperature does not exceed +175°C.
 - b. The power dissipation does not exceed 1.2 W.
 - 4.4 Conformance inspection. Conformance inspection shall be in accordance with MIL-PRF-19500, and as specified herein.

- 4.4.1 <u>Group A inspection</u>. Group A inspection shall be conducted in accordance with MIL-PRF-19500, and table I herein. The following test conditions shall be used for $Z_{\theta JX}$, group A inspection:
 - a. I_M measurement current......1 mA 10 mA.
 - b. I_H forward heating current......1.0 A 2.0 A.
 - c. t_H heating time......10 ms.
 - d. t_{MD} measurement delay time......70 μs maximum.
- 4.4.2 <u>Group B inspection</u>. Group B inspection shall be conducted in accordance with the conditions specified for subgroup testing in table VIb (JAN, JANTX, and JANTXV) of MIL-PRF-19500, and as follows. Electrical measurements (endpoints) shall be in accordance with the applicable footnotes and steps of table III herein.

Subgroup	Method	Condition
B2	4066	See 4.5.1.
В3	1027	I_Z = I_{ZM} column 8 of table IV; T_A = +30°C \pm 5°C.
B4		Not applicable.
B5		Not applicable.

4.4.3 <u>Group C inspection</u>. Group C inspection shall be conducted in accordance with the conditions specified for subgroup testing in table VII of MIL-PRF-19500, and as follows. Electrical measurements (endpoints) shall be in accordance with the applicable footnotes and steps of table III herein.

Subgroup	Method	Condition
C2	2036	Terminal strength: Test condition A; weight = 4 lbs; t = 15 seconds. Terminal strength: Test condition E.
C3		Applies to D0-13 devices only.
C6	1026	$I_Z = I_Z$ column 8 of table IV; $T_A = +30^{\circ}C \pm 5^{\circ}C$.
C7	4071	$I_Z = I_Z$ column 5 of table IV; $T_A = +25^{\circ}C \pm 5^{\circ}C$; $T_2 = +125^{\circ}C \pm 5^{\circ}C$; $\alpha V_Z =$ column 15 of table IV; 22 devices, $c = 0$.

- 4.5 Methods of inspection. Methods of inspection shall be as specified in the appropriate tables and as follows:
- 4.5.1 <u>Surge current (I_{ZSM})</u>. The peak currents shown in column 10 of table IV shall be applied in the reverse direction and these shall be superimposed on the current ($I_Z = I_{Z1}$) (column 5 of table IV) a total of 5 surges at 1 minute intervals. Each individual surge shall be one-half square-wave-pulse of 1/120 second duration or an equivalent one-half sine wave with the same effective rms current.
- 4.5.2 Regulator voltage measurements. The test current shall be applied until thermal equilibrium is attained (90 seconds maximum) prior to reading the breakdown voltage. For this test, the surface mount device shall be mounted at the endcaps and the axial leaded device shall be suspended by its leads with mounting clips whose inside edge is located at 0.375 inch (9.53 mm) from the body and the mounting clips shall be maintained at a temperature of +25°C +8°C, -2°C. This measurement may be performed after a shorter time following application of the test current than that which provides thermal equilibrium if correlation to stabilized readings can be established to the satisfaction of the Government.
- 4.5.3 <u>Temperature coefficient of regulator voltage (αV_Z) </u>. The device shall be temperature stabilized with current applied prior to reading regulator voltage at the specified ambient temperature as specified in 4.4.3, group C, subgroup 7.

- 4.5.4 <u>Voltage regulation V_Z (reg)</u>. Voltage regulation shall be determined by the difference of the regulator voltage measured at different currents as specified in table I, group A, subgroup 7. Both tests shall be performed at thermal equilibrium. This ΔV_Z shall not exceed column 9 of table IV.
- 4.5.5 <u>Thermal impedance $Z_{\theta JX}$ measurements for screening</u>. The $Z_{\theta JX}$ measurements shall be performed in accordance with MIL-STD-750, method 3101. The maximum limit (not to exceed the group A, subgroup 2 limit) for $Z_{\theta JX}$ in screening (table IV of MIL-PRF-19500) shall be derived by each vendor by means of statistical methods.
- 4.5.5.1 For initial qualification or requalification. Read and record data ($Z_{\theta,JX}$) shall be supplied to the qualifying activity on one lot (random sample of 500 devices minimum). Twenty-two serialized devices shall be sent to the qualifying activity for test correlation.
- 4.5.6 <u>Thermal resistance</u>. Thermal resistance measurement shall be in accordance with MIL-STD-750, method 3101 or 4081. Forced moving air or draft shall not be permitted across the device during test. The maximum limit for $R_{\theta JL}$ under these test conditions shall be $R_{\theta JL}$ (max) = 80°C/W (D0-13), $R_{\theta JL}$ (max) = 50°C/W (D0-41), or $R_{\theta JEC}$ = 50°C/W. The following conditions shall apply when using method 3101:
 - a. I_M 1 mA to 10 mA.
 - b. I_H 0.5 A to 1.0 A.
 - c. t_H 25 seconds minimum.
 - d. t_{MD} 70 μs maximum.

LS = Lead spacing = 3/8 inch as defined on figure 6 below:

LS = 0 inches for "UR" suffix devices.

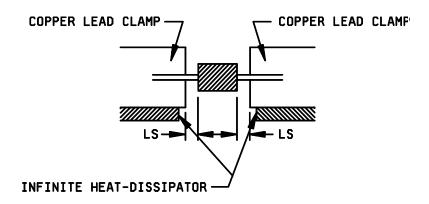


FIGURE 6. Mounting conditions.

4.5.6.1 For initial qualifications and requalifications. Read and record data in accordance with group E herein and shall be included in the qualification report.

TABLE I. Group A inspection.

		MIL-STD-750		Units	<u>2</u> /	
Inspection 1/	Method	Conditions	Symbol	Min	Max	Unit
Subgroup 1 Visual and mechanical examination	2071					
Subgroup 2 Forward voltage Reverse current	4011 4016	I_F = 200 mA dc DC method; V_R = column 11 of table IV	V _F I _{R1}		1.2 Column 12	V dc μA dc
Regulator voltage (see 4.5.2)	4022	$I_{Z1} = I_Z = $ (column 5 of table IV)	VZ	Column 3	Column 4	V dc
Thermal impedance	3101	See 4.5.5 (-1 devices only)	$z_{\theta JX}$		15	°C/W
Subgroup 3 High-temperature operation Reverse current (-1 devices only)	4016	T _A = +150°C DC method: V _R = column 11 of table IV	I _{R2}		Column 14	μA dc
Subgroup 4 Small-signal reverse breakdown impedance Small-signal knee impedance	4051 4051	I_Z = column 5 of table IV; I_{sig} = 10 percent of I_Z I_{ZK} = column 16 of table IV; I_{sig} = 10 percent of I_{ZK}	Z _Z Z _{ZK}		Column 6 Column 7	ohms ohms
Subgroups 5. and 6 Not applicable						
Subgroup 7 Voltage regulation (see 4.5.4)		I _Z = 10 percent of column 8 of table IV (current 1) I _Z = 50 percent of column 8 of table IV (current 2)	V _Z (reg)		Column 9	V dc

 $[\]underline{1}\!/$ For sampling plan, see MIL-PRF-19500 $\underline{2}\!/$ Column references are to table IV herein.

TABLE II. Group E inspection (all product assurance levels).

		MIL-STD-750	Qualification conformance
Inspection 1/	Method	Conditions	Inspection (LTPD)
Subgroup 1 Temperature cycling Electrical measurements	1051	500 cycles See table III, Steps 1, 2, 3, and 5	45 devices, c = 0
Subgroup 2 Intermittent life Electrical measurements	1037	6,000 cycles See table III, steps 1, 2, and 3	45 devices, c = 0
Subgroup 3 Not applicable			
Subgroup 4 Thermal resistance surface mount Thermal resistance leaded	3101 or 4081 3101 or 4081	R0JEC = 50° C/W (maximum) at zero lead length. $+25^{\circ}$ C \leq TR \leq $+35^{\circ}$ C, (see 4.5.6) R0JL = 80° C/W (maximum) at 0.375 lead length. $+25^{\circ}$ C \leq TR \leq $+35^{\circ}$ C, (see 4.5.6)	22 devices, c=0 22 devices, c=0

^{1/} A separate sample may be pulled for each test.

TABLE III. Group A, B, C, and E electrical end-point measurements. 1/2/3/

			MIL-STD-750		Limits	1/	
Step	Inspection	Method	Conditions	Symbol	Min	Max	Unit
1.	Reverse current	4016	DC method, V _R = column 11 of table IV	I _{R1}		Column 12	μA dc
2	Reverse current	4016	DC method, VR = column 11 of table IV	I _{R3}		Column 13	μA dc
3.	Breakdown voltage (see 4.5.2)	4022	I _Z = column 5 of table IV	VZ	Column 3	Column 4	V dc
4.	Small-signal breakdown impedance	4051	I_Z = column 5 I_{sig} = 10 percent of I Z	ZZ		Column 6	ohms
5.	Thermal impedance	3101	See 4.5.5	$Z_{\theta JX}$		15	°C/W

 $[\]underline{1}\!\!/$ Column references are to table IV herein.

- $\underline{2}\!/$ The electrical measurements for table VIb (JAN, JANTX, and JANTXV) of MIL-PRF-19500 are as follows:
 - a. Subgroup 2, see table III herein, steps 1, 3, 4, and 5.
 - b. Subgroups 3 and 6, see table III herein, steps 2, 3, and 4.
- $\underline{3}$ / The electrical measurements for table VII of MIL-PRF-19500 are as follows:
 - a. Subgroup 2, see table III herein, steps 1, 3, 4, and 5.
 - b. Subgroup 3, (D0-13 devices only), see table III herein, steps 1, 3, and 4.
 - c. Subgroup 6, see table III herein, steps 2, 3, and 4.

TABLE IV. Test ratings for diodes, types 1N3821A through 1N3828A and 1N3016B through 1N3051B (5 percent tolerance).

_																									
Col 16	Izk Test current	mA	1.0 1.0 1.0	1.0	0.1	1.0	1.0	0.5	0.5	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25
Col 15	αVZ Temperature coefficient	J./%	-0.075 070 060	050 ± .025	±.030 +.040	+ .050	+ .057 + .061	+ .065	+ .068	+ .071	+ .073	970:+	+.082	+ .083	+ .085 + .086	+ .087	+ .088	060. +	+ .092	+.091	+ + 093 + 094	+ .095	+ .095	960. +	960: +
Col 14	(-1 only) IR2 Reverse current dc; $T_A = +150^{\circ}C$	Рη	200 150 100	50 50	20 20	50	50 50	50	20	50	6	2 0	10	10	0 0 0	10	10	10	10	5 5	2 6	10	10	10	10
Col 13	IR3 Reverse current dc	1-1 AM	150 100 40	10	<u> </u>	9	100	10	10	10	4 -	t 0	7	7	0 0	2	2	7	7	2 0	7 0	2	2	7	7
Col	IR3 Recurre	non-1 µA	200 200 100	20 20	20	20	300	100	20	20	50	20	20	20	2 2	20	20	20	50	20	20	20	20	20	20
12	verse nt dc	-1 µA	100 75 25	5	ო ო	က	5.0	5.0	2.0	5.0	0. 6	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5
Col 12	IR1 Reverse current dc	non -1 µA	100 100 50	10	9 9	10	150	20	52	25	ę 2	2 0	10	10	9 9	10	10	10	10	0 7	2 0	10	10	10	10
Col 11	VR Reverse voltage	Volts			- 2	ო	5.2 5.7	6.2	6.9	7.6	4. 6	- o.	4.11	12.2	13.7	16.7	18.2	20.6	22.8	25.1	29.7	32.7	35.8	38.8	32.6
Col 10	IR (Surge) T _A = +25°C	mA	1380 1260 1190	1070 970	890 810	730	740 680	009	540	480	420	370	320	300	260 240	210	200	170	160	150	110	100	92	06	82
Col 9	Vz (reg)	Volts	1.00 0.80 0.75	0.70	0.50	0:30	0.30	0.40	0.45	0.50	0.55	0.65	0.75	0.80	0.83 0.95	1.0	1.1	1.3	4.	7.5	- 6	1.9	2.1	2.3	2.5
Col 8	IZM Max dc current	mA	276 252 238	213 194	178 162	146	140 125	115	105	92	82	8 4	63	09	52 47	43	40	34	31	28	23	21	19	18	17
Col 7	ZZK Knee impedance	swyo	400 400 400	400 500	550 600	200	700 700	200	200	200	200	00/	200	200	750 750	750	750	750	1000	1000	1000	1500	1500	1500	2000
Col 6	ZZ Impedance	ohms	10 10 9	6 8	7	7	3.5 4.0	4.5	0.9	7	∞ σ	9	4	16	50 50 50 50 50 50 50 50 50 50 50 50 50 5	23	22	32	9 !	54 0	3 8	20	80	92	110
Col 5	IZ Test current	mA	76 69 64	58 53	49 45	4	37 34	31	28	25	23	19	17	15.5	14.0 12.5	11.5	10.5	9.2	8.5	7.5	0.7	0.9	5.5	5.0	4.5
Col 4	VZ Max <u>2</u> /	Volts	3.46 3.78 4.09	4.51	5.35 5.88	6.51	7.14	8.61	9.55	10.5	11.55	13.65	15.75	16.80	18.90 21.0	23.1	25.2	28.3	31.5	34.6	9.75	45.1	49.3	53.5	58.8
Col 3	VZ Min	Volts	3.14 3.42 3.71	4.09	4.85 5.32	5.89	6.46	7.79	8.65	9.2	10.45	12.35	14.25	15.20	17.10 19.0	20.9	22.8	25.7	28.5	31.4	37.1	40.9	44.7	48.5	53.2
Col 2	VZ Nom 2/	Volts	3.3 3.6 3.9	4.3	5.1 5.6	6.2	6.8	8.2	9.1	9	, ;	<u>τ</u> τ	15	16	18 20	22	24	27	30	33	9 68	43	47	51	26
Col 1	Voltage Group 1/ 2/		1N3821A 1N3822A 1N3823A	1N3824A 1N3825A	1N3826A 1N3827A	1N3828A	1N3016B 1N3017B	1N3018B	1N3019B	1N3020B	1N3021B	1N3023B	1N3024B	1N3025B	1N3026B 1N3027B	1N3028B	1N3029B	1N3030B	1N3031B	1N3032B	1N3034B	1N3035B	1N3036B	1N3037B	1N3038B

See footnotes at end of table

TABLE IV. Test ratings for diodes, types 1N3821A through 1N3828A and 1N3016B through 1N3051B (5 percent tolerance).- Continued

Col 16	IZK Test current*	mA	0.25 0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25	0.25
Col 15	αVZ Temperature coefficient*	S∘/%	+0.097 +0.097	+0.098	+0.098	+0.099	+0.100	+0.100	+0.100	+0.100	+0.100	+0.100	+0.100
Col 14	(-1 only) IR2 Reverse current dc; $T_A = +150^{\circ}C$	βή	10 10	10	10	10	10	10	10	10	10	10	10
Col 13 IR3 Reverse current dc	everse nt dc	-1 µA	2	2	2	2	2	7	7	7	2	2	7
	IR3 Re curre	non -1 µA	20 20	20	20	20	20	20	20	20	20	20	20
12	verse t dc*	-1 µА	0.5	0.5	0.5	9.0	0.5	0.5	0.5	0.5	0.5	0.5	0.5
Col 12	IR1 Reverse current dc*	non -1 μΑ	10 10	10	10	10	10	10	10	10	10	10	10
Col 11	VR Reverse voltage	Volts	47.1 51.7	26.0	62.2	Ø.68	83.6	91.2	98.8	114.0	121.6	136.8	152.0
Col 10	IR (Surge) T _A = +25°C	mA	75 70	63	58	99	42	40	35	29	27	25	23
Col 9	Vz (reg)	Volts	2.7 3.0	3.3	3.6	4.0	5.0	5.5	0.9	7.0	8.0	10.0	12.0
Col 8	I ZM Max dc current	mA	15 14	12	11	(B)	8.3	8.0	6.9	2.7	5.4	6.4	4.6
Col 7	ZZK Knee impedance	ohms	2000 2000	2000	3000	3000	4000	4500	2000	0009	6500	2000	8000
Col 6	ZZ impedance	ohms	125 150	175	200	320	450	550	200	1000	1100	1200	1500
Col 5	IZ Test current	mA	4.0 3.7	3.3	3.0	2.8	2.3	2.0	1.9	1.7	1.6	1.4	1.2
Col 4	VZ Max <u>2</u> /	Volts	65.1 71.4	78.7	86.1	965	115.5	126	136.5	157.5	168	189	210
Col 3	VZ Min	Volts	58.95 64.60	71.35	77.95	96.9	104.5	114	123.5	142.5	152	171	190
Col 2	VZ Nom	Volts	62 68	75	82	0061	110	120	130	150	160	180	200
Col 1	Voltage Group $\frac{1}{2}$		1N3039B 1N3040B	1N3041B	1N3042B	1N3048B	1N3045B	1N3046B	1N3047B	1N3048B	1N3049B	1N3050B	1N3051B

^{1/} Ratings also apply to dash one and surface mount devices unless otherwise noted.

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5 percent voltage tolerances are shown in table.
For 2 percent tolerance ("C" suffix; for "-1" suffix and JANHC only), column 3 is 2 percent less than column 2, column 4 is 2 percent more than column 2.
For 1 percent tolerance ("D" suffix; for "-1" suffix and JANHC only), column 3 is 1 percent less than column 2, column 4 is 1 percent more than column 2.

5. PACKAGING

- 5.1 <u>Packaging</u>. For acquisition purposes, the packaging requirements shall be as specified in the contract or order (see 6.2). When actual packaging of material is to be performed by DoD personnel, these personal need to contact the responsible packaging activity to ascertain requisite packaging requirements. Packaging requirements are maintained by the Inventory Control Points' packaging activity within the Military Department or Defense Agency, or within the Military Departments' System Command. Packaging data retrieval is available from the managing Military Departments' or Defense Agencys' automated packaging files, CD-ROM products, or by contacting the responsible packaging activity.
 - 5.2 Marking. Unless otherwise specified (see 6.2), marking shall be in accordance with MIL-STD-129.

NOTES:

(This section contains information of a general or explanatory nature that may be helpful, but is not mandatory.)

- 6.1 Notes. The notes specified in MIL-PRF-19500 are applicable to this specification.
- 6.2 Acquisition requirements. Acquisition documents should specify the following:
 - a. Issue of DODISS to be cited in the solicitation.
 - b. Lead finish (see 3.3.1).
 - c. For die acquisition, the JANHC letter version should be specified (see figures 4 and 5).
 - d. Product assurance level and type designation.
- 6.3 <u>Substitution information</u>. Device types 1N3821A through 1N3828A and 1N3016B through 1N3051B (excluding JANHC devices) are inactive for new design as of the date of this specification. The corresponding dash-one suffix device should be used for new design.
- 6.3.1 <u>Substitutability of 2 percent and 1 percent tolerance devices</u>. Devices of tighter tolerance are a direct one way substitute for the looser tolerance devices (example: JANTX1N3821D-1 substitutes for JANTX1N3821A-1).
- 6.4 <u>Suppliers of JANHC die.</u> The qualified JANHC suppliers with the applicable letter version (example JANHCA1N3821A) will be identified on the QPL.

JANHC ordering information						
PIN	Manufacturer CAGE					
	55801	12954				
1N3821A through 1N3828A	JANHCA1N3821A through JANHCA1N3828A	JANHCB1N3821A through JANHCB1N3828A				
1N3016B through 1N3051B	JANHCA1N3016B through JANHCA1N3051B	JANHCB1N3016B through JANHCB1N3051B				

NOTE: C and D tolerance suffix are applicable to JANHC.

- 6.5 Qualification. With respect to products requiring qualification, awards will be made only for products which are, at the time of award of contract, qualified for inclusion in Qualified Products List QPL-19500 whether or not such products have actually been so listed by that date. The attention of the contractors is called to these requirements, and manufacturers are urged to arrange to have the products that they propose to offer to the Federal Government tested for qualification in order that they may be eligible to be awarded contracts or purchase orders for the products covered by this specification. Information pertaining to qualification of products may be obtained from Defense Supply Center Columbus, DSCC-VQE, Columbus, OH 43216.
- 6.6 <u>Changes from previous issue</u>. Asterisks are not used in this revision to identify changes with respect to the previous issue due to the extent of the changes.

Custodians:

Army - CR Navy - EC Air Force - 17 NASA - NA Preparing activity: DLA - CC

(Project 5961-1677)

Review activities:

Army - AR, AV, MI, SM Navy - AS, CG, MC Air Force - 13, 19, 85, 99

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INSTRUCTIONS							
 The preparing activity must complete blocks 1, 2, 3, and 8. In block 1, both the document number and revision letter should be given. 							
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I RECOMMEND A CHANGE:	1. DOCUMENT NUMBER MIL-PRF-19500/115J	2. DOCUMENT DATE (YYMMDD) 97/10/10					
3. DOCUMENT TITLE SEMICONDUCTOR DEVICE, DIODE, SILICON, VOLTAGE REGULATOR TYPES 1N3821A THROUGH 1N3828A, 1N3016B THROUGH 1N3051B, 1N3821A-1 THROUGH 1N3828A-1, 1N3016B-1 THROUGH 1N3051B-1, 1N3821AUR-1 THROUGH 1N3828AUR-1, 1N3016BUR-1 THROUGH 1N3051BUR-1, PLUS C- AND D- TOLERANCE SUFFIX, JAN, JANTSX, JANTXV, AND JANHC							
4. NATURE OF CHANGE (Identify paragraph number and include proposed rewrite, if possible. Attach extra sheets as needed.)							
S. DEACON FOR DECOMMENDATION							
5. REASON FOR RECOMMENDATION							
6. SUBMITTER							
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c. ADDRESS (Include Zip Code)	d. TELEPHONE (Include Area Code)	7. DATE SUBMITTED					
	(1) Commercial	(YYMMDD)					
	(2) AUTOVON (If applicable)						
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a. NAME Al Barone	b. TELEPHONE (Include Area Code) (1) Commercial (2) AUTOVON 614-692-0510 850-0510						
c. ADDRESS (Include Zip Code) Defense Supply Center Columbus ATTN: DSCC-VAT Columbus, OH 43232	IF YOU DO NOT RECEIVE A REPLY WITHIN 45 DAYS, CONTACT: Defense Quality and Standardization Office 5203 Leesburg Pike, Suite 1403, Falls Church, VA 22041-3466 Telephone (703) 756-2340 AUTOVON 289-2340						

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